



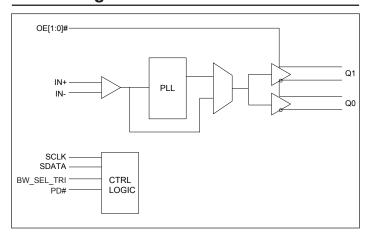
**Very Low Power 2-Output PCIe Clock Buffer** 

## **Description**

The DIODES PI6CB18200 is an 2-output very low power PCIe® Gen1/Gen2/Gen3/Gen4 clock buffer. It takes an reference input to fanout two 100MHz low power differential HCSL outputs. Individual OE pin for each output provides easier power management.

It uses Diodes proprietary PLL design to achieve very low jitter that meets PCIe Gen1/Gen2/Gen3/Gen4 requirements. Other than PCIe 100MHz support, this device also support Ethernet application with 50MHz or 125MHz via SMBus. It provides various options such as different slew rate and amplitude through strapping pins or SMBUS so that users can configure the device easily to get the optimized performance for their individual boards.

### **Block Diagram**



### **Features**

- 1.8V Supply Voltage
- HCSL Input: 100MHz, also support 50MHz or 125MHz via SMBus
- 2 Differential Low Power HCSL Outputs
- Individual Output Enable
- Programmable Slew Rate and Output Amplitude for each output
- Differential Outputs blocked until PLL is locked
- Strapping Pins or SMBus for Configuration
- 3.3V Tolerant SMBus Interface Support
- Very Low Jitter Outputs
  - Differential Cycle-to-cycle Jitter <50ps</li>
  - Differential Output-to-output Skew <50ps</li>
  - PCIe Gen1/Gen2/Gen3/Gen4 Compliant
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- Packaging (Pb-free & Green):
  - 24-lead 4×4mm TQFN

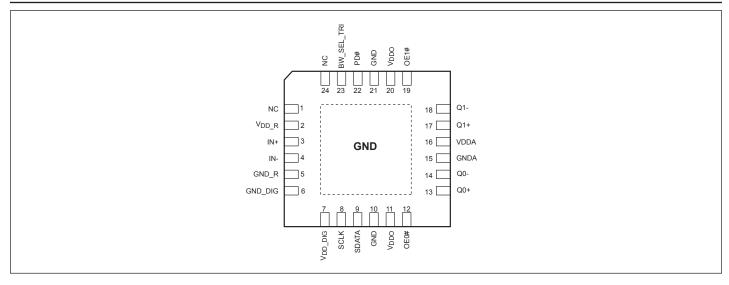
### Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





# **Pin Configuration**



# **Pin Description**

| Pin Number | Pin Name             | Ту               | pe   | Description   |
|------------|----------------------|------------------|------|---|
| 1, 24      | NC                   |                  |      | Internal connected for feedback loop. Do not connect this pin   |
| 2          | V <sub>DD</sub> _R   | Power            |      | Power supply for input differential buffers   |
| 3          | IN+                  | Input            |      | Differential true clock input   |
| 4          | IN-                  | Input            |      | Differential complementary clock input  |
| 5          | GND_R                | Power            |      | Ground for input differential buffers   |
| 6          | GND_DIG              | Power            |      | Ground for digital circuitry  |
| 7          | V <sub>DD</sub> _DIG | Power            |      | Power supply for digital circuitry, nominal 1.8V  |
| 8          | SCLK                 | Input            | CMOS | SMBUS clock input, 3.3V tolerant  |
| 9          | SDATA                | Input/<br>Output | CMOS | SMBUS Data line, 3.3V tolerant  |
| 10, 21     | GND                  | Power            |      | Ground  |
| 11, 20     | $V_{\mathrm{DDO}}$   | Power            |      | Power supply for differential outputs   |
| 12         | OE0#                 | Input            | CMOS | Active low input for enabling Q0 pair. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs |
| 13         | Q0+                  | Output           | HCSL | Differential true clock output  |
| 14         | Q0-                  | Output           | HCSL | Differential complementary clock output   |
| 15         | GNDA                 | Power            |      | Ground for analog circuitry   |
| 16         | $V_{\mathrm{DDA}}$   | Power            |      | Power supply for analog circuitry   |
| 17         | Q1+                  | Output           | HCSL | Differential true clock output  |
| 18         | Q1-                  | Output           | HCSL | Differential complementary clock output   |
| 19         | OE1#                 | Input            | CMOS | Active low input for enabling Q1 pair. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs |





| Pin Number | Pin Name   | Туре  |           | Description   |
|------------|------------|-------|-----------|---|
| 22         | PD#        | Input | CMOS      | Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal pull-up resistor. |
| 23         | BW_SEL_TRI | Input | Tri-level | Latch to select low loop bandwidth, bypass PLL, and high loop bandwidth. This pin has both internal pull-up and pull-down   |

## **Power Management Table**

| PD# | IN      | SMBus OE bit | OEn# | Qn+     | Qn-     | PLL Status        |
|-----|---------|--------------|------|---------|---------|-------------------|
| 0   | X       | X            | X    | Low     | Low     | Off               |
| 1   | Running | 0            | X    | Low     | Low     | On <sup>(1)</sup> |
| 1   | Running | 1            | 0    | Running | Running | On <sup>(1)</sup> |
| 1   | Running | 1            | 1    | Low     | Low     | On <sup>(1)</sup> |

Note:

## **PLL Operating Mode Select Table**

| BW_SEL_TRI | Operating Mode          | Byte1 [7:6] Readback | Byte1 [4:3] Readback |
|------------|-------------------------|----------------------|----------------------|
| 0          | PLL with low Bandwidth  | 00                   | 00                   |
| M          | PLL Bypass              | 01                   | 01                   |
| 1          | PLL with high Bandwidth | 11                   | 11                   |

# **Frequency Select Table**

| Freq. Select Byte 3 [4:3] | IN (MHz) | Qn (MHz) |
|---------------------------|----------|----------|
| 00 (default)              | 100      | 100      |
| 01                        | 50       | 50       |
| 10                        | 125      | 125      |
| 11                        | Reserved | Reserved |

## **SMBUS Address**

| Address | + Read/ Write bit |
|---------|-------------------|
| 1101101 | X                 |

<sup>1.</sup> If PLL Bypass mode is selected, the PLL will be off and outputs will be running.





# **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

| Storage Temperature65°C to +150°C                                   |
|---|
| Junction Temperatureup to +125°C                                    |
| Supply Voltage to Ground Potential, V <sub>DDxx</sub> 0.5V to +2.5V |
| Input Voltage –0.5V to V <sub>DD</sub> +0.5V, not exceed 2.5V       |
| SMBus, Input High Voltage   |
| ESD Protection (HBM)  |

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **Operating Conditions**

Temperature = TA; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol  | Parameters   | Conditions  | Min. | Тур. | Max. | Units |
|---|--|---|------|------|------|-------|
| V <sub>DD</sub> , V <sub>DDA</sub> ,<br>V <sub>DD</sub> R,<br>V <sub>DD</sub> DIG | Power Supply Voltage                                     |   | 1.7  | 1.8  | 1.9  | V     |
| $V_{\mathrm{DDO}}$  | Output Power Supply Voltage                              |   | 1.7  | 1.8  | 1.9  | V     |
| $I_{DDA}$   | Analog Power Supply Current                              | $V_{DDA}$ + $V_{DD}$ _R, PLL mode, All outputs active @100MHz               |      | 4.5  | 6    | mA    |
| $I_{DD}$  | Power Supply Current                                     | $V_{DD}$ + $V_{DD\_DIG}$ , All outputs active @100MHz                       |      | 8    | 10   | mA    |
| $I_{\mathrm{DDO}}$  | Power Supply Current for Outputs                         | All outputs active @100MHz  |      | 6    | 8    | mA    |
| I <sub>DDA_PD</sub>   | Analog Power Supply Power<br>Down <sup>(1)</sup> Current | V <sub>DDA</sub> + V <sub>DD</sub> _R, PLL mode, All outputs active @100MHz |      | 0.7  | 1    | mA    |
| I <sub>DD_PD</sub>  | Power Supply Power Down <sup>(1)</sup><br>Current        | $V_{DD}$ + $V_{DD\_DIG+}$ $V_{DDO}$ , All outputs LOW/LOW                   |      |      | 1.4  | mA    |
| T <sub>A</sub>  | Ambient Temperature                                      | Industrial grade  | -40  |      | 85   | °C    |

### Note:

# **Input Electrical Characteristics**

| Symbol           | Parameters                    | Conditions | Min. | Тур. | Max. | Units |
|------------------|-------------------------------|------------|------|------|------|-------|
| R <sub>pu</sub>  | Internal pull up resistance   |            |      | 120  |      | ΚΩ    |
| R <sub>dn</sub>  | Internal pull down resistance |            |      | 120  |      | ΚΩ    |
| L <sub>PIN</sub> | Pin inductance                |            |      |      | 7    | nН    |

<sup>1.</sup> Input clock is not running.





## **SMBus Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol               | Parameters                | Conditions   | Min.                       | Тур. | Max. | Units |
|----------------------|---------------------------|--|----------------------------|------|------|-------|
| V <sub>DDSMB</sub>   | Nominal bus voltage       |  | 1.7                        |      | 3.6  | V     |
|                      |                           | SMBus, $V_{DDSMB} = 3.3V$                                    | 2.1                        |      | 3.6  |       |
| V <sub>IHSMB</sub>   | SMBus Input High Voltage  | SMBus, $V_{DDSMB} < 3.3V$                                    | 0.65<br>V <sub>DDSMB</sub> |      |      | V     |
| 17                   | SMBus Input Low Voltage   | SMBus, $V_{DDSMB} = 3.3V$                                    |                            |      | 0.6  | V     |
| V <sub>ILSMB</sub>   |                           | SMBus, V <sub>DDSMB</sub> < 3.3V                             |                            |      | 0.6  |       |
| I <sub>SMBSINK</sub> | SMBus sink current        | SMBus, at V <sub>OLSMB</sub>                                 | 4                          |      |      | mA    |
| V <sub>OLSMB</sub>   | SMBus Output Low Voltage  | SMBus, at I <sub>SMBSINK</sub>                               |                            |      | 0.4  | V     |
| f <sub>MAXSMB</sub>  | SMBus operating frequency | Maximum frequency  |                            |      | 400  | kHz   |
| t <sub>RMSB</sub>    | SMBus rise time           | (Max V <sub>IL</sub> - 0.15) to (Min V <sub>IH</sub> + 0.15) |                            |      | 1000 | ns    |
| t <sub>FMSB</sub>    | SMBus fall time           | (Min $V_{IH}$ + 0.15) to (Max $V_{IL}$ - 0.15)               |                            |      | 300  | ns    |

## **LVCMOS DC Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol            | Parameters         | Conditions   | Min.                    | Тур.            | Max.                    | Units |
|-------------------|--------------------|--|-------------------------|-----------------|-------------------------|-------|
| $V_{\mathrm{IH}}$ | Input High Voltage | Single-ended inputs, except SMBus  | 0.75<br>V <sub>DD</sub> |                 | V <sub>DD</sub><br>+0.3 | V     |
| V <sub>IM</sub>   | Input Mid Voltage  | BW_SEL_TRI   | $0.4 V_{ m DD}$         | $0.5 V_{ m DD}$ | $0.6 V_{ m DD}$         | V     |
| $V_{\mathrm{IL}}$ | Input Low Voltage  | Single-ended inputs, except SMBus  | -0.3                    |                 | 0.25<br>V <sub>DD</sub> | V     |
| I <sub>IH</sub>   | Input High Current | Single-ended inputs, $V_{IN} = V_{DD}$   |                         |                 | 20                      | μA    |
| $I_{IL}$          | Input Low Current  | Single-ended inputs, $V_{IN} = 0V$   | -20                     |                 |                         | μA    |
| $I_{IH}$          | Input High Current | Single-ended inputs with pull up / pull down resistor, $V_{\rm IN}$ = $V_{\rm DD}$ |                         |                 | 220                     | μΑ    |
| $I_{IL}$          | Input Low Current  | Single-ended inputs with pull up / pull down resistor, $V_{IN} = 0V$               | -220                    |                 |                         | μА    |
| $C_{\rm IN}$      | Input Capacitance  |  | 1.5                     |                 | 5                       | pF    |

## **LVCMOS AC Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol             | Parameters            | Conditions   | Min. | Тур. | Max. | Units  |
|--------------------|-----------------------|--|------|------|------|--------|
| t <sub>OELAT</sub> | Output enable latency | Q start after OE# assertion Q stop after OE# deassertion | 1    |      | 3    | clocks |
| t <sub>PDLAT</sub> | PD# de-assertion      | Differential outputs enable after PD# deassertion        |      | 20   | 300  | us     |





# **HCSL Input Characteristics(1)**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol             | Parameters                              | Conditions   | Min. | Тур. | Max.  | Units |
|--------------------|---|--|------|------|-------|-------|
| V <sub>IHDIF</sub> | Diff. Input High Voltage <sup>(3)</sup> | IN+, IN-, single-end measurement   | 600  | 800  | 1150  | mV    |
| V <sub>ILDIF</sub> | Diff. Input Low Voltage <sup>(3)</sup>  | IN+, IN-, single-end measurement   | -300 | 0    | 300   | mV    |
| V <sub>COM</sub>   | Diff. Input Common Mode<br>Voltage      |  | 150  |      | 1000  | mV    |
| V <sub>SWING</sub> | Diff. Input Swing Voltage               | Peak to peak value (V <sub>IHDIF</sub> - V <sub>ILDIF)</sub>                                       | 300  |      | 1450  | mV    |
| f <sub>INBP</sub>  | Input Frequency                         | PLL Bypass mode  | 1    |      | 200   | MHz   |
| f <sub>IN100</sub> | Input Frequency                         | 100MHz PLL   | 60   | 100  | 110   | MHz   |
| f <sub>IN125</sub> | Input Frequency                         | 125MHz PLL   | 75   | 125  | 137.5 | MHz   |
| f <sub>IN156</sub> | Input Frequency                         | 50MHz PLL  | 30   | 50   | 65    | MHz   |
| t <sub>STAB</sub>  | Clock stabilization                     | From $V_{\rm DD}$ Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock |      | 0.6  | 1.0   | ms    |
| t <sub>RF</sub>    | Diff. Input Slew Rate <sup>(2)</sup>    | Measured differentially  | 0.4  |      |       | V/ns  |
| I <sub>IN</sub>    | Diff. Input Leakage Current             | $V_{IN} = V_{DD}, V_{IN} = GND$  | -5   | 0.01 | 5     | uA    |
| $t_{DC}$           | Diff. Input Duty Cycle                  | Measured differentially  | 45   |      | 55    | %     |
| tj <sub>c-c</sub>  | Diff. Input Cycle to cycle jitter       | Measured differentially  |      |      | 125   | ps    |

### Note:

- 1. Guaranteed by design and characterization, not 100% tested in production
- 2. Slew rate measured through +/-75mV window centered around differential zero
- 3. The device can be driven by a single-ended clock by driving the true clock and biasing the complement clock input to the Vbias, where Vbias is  $(V_{IH}-V_{IL})/2$

## **HCSL Output Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol            | Parameters  | Condition                                | Min. | Тур. | Max. | Units |
|-------------------|---|--|------|------|------|-------|
| V <sub>OH</sub>   | Output Voltage High <sup>(1)</sup>                  | Statistical measurement on single-ended  | 660  | 774  | 900  | mV    |
| V <sub>OL</sub>   | Output Voltage Low <sup>(1)</sup>                   | signal using oscilloscope math function  | -150 |      | 150  | mV    |
| V <sub>OMAX</sub> | Output Voltage Maximum <sup>(1)</sup>               | Measurement on single ended signal using |      | 821  | 1150 | mV    |
| V <sub>OMIN</sub> | Output Voltage Minimum <sup>(1)</sup>               | absolute value                           | -300 | -15  |      | mV    |
| Voswing           | Output Swing Voltage <sup>(1,2,3)</sup>             | Scope averaging off                      | 300  | 1536 |      | mV    |
| V <sub>OC</sub>   | Output Cross Voltage(1,2,4)                         |  | 250  | 430  | 550  | mV    |
| DV <sub>OC</sub>  | V <sub>OC</sub> Magnitude Change <sup>(1,2,5)</sup> |  |      | 12   | 140  | mV    |

### Note:

- 1. At default SMBUS amplitude settings
- 2. Guaranteed by design and characterization, not 100% tested in production
- 3. Measured from differential waveform
- $4. \ \, \text{This one is defined as voltage where Q+} = \text{Q-measured on a component test board and only applied to the differential rising edge}$
- 5. The total variation of all Vcross measurements in any particular system. This is a subset of Vcross\_min/max allowed.





# **HCSL Output AC Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

| Symbol               | Parameters   | Condition  | Min. | Тур. | Max. | Units |
|----------------------|--|--|------|------|------|-------|
| f <sub>OUT</sub>     | Output Frequency   |  |      | 100  |      | MHz   |
| DIAZ                 | DI I 1 : 1.1 (1.8)   | -3dB point in High Bandwidth Mode  | 2    | 2.7  | 4    | MHz   |
| BW                   | PLL bandwidth <sup>(1,8)</sup>   | -3dB point in Low Bandwidth Mode   | 1    | 1.4  | 2    | MHz   |
| tj <sub>peak</sub>   | PLL Jitter Peaking   | Peak pass band gain  |      | 1.2  | 2    | dB    |
| 4                    | Slew rate <sup>(1,2,3)</sup>   | Scope averaging on fast setting  | 2.2  | 3.0  | 6    | V/ns  |
| $t_{RF}$             | Siew rate  | Scope averaging on slow setting  | 0.4  | 2    | 3    | V/ns  |
| $Dt_{RF}$            | Slew rate matching <sup>(1,2,4)</sup>  | Scope averaging on   |      | 7    | 20   | %     |
| t <sub>SKEW</sub>    | Output Skew <sup>(1,2)</sup>   | Averaging on, $V_T = 50\%$   |      | 43   | 50   | ps    |
|                      | D (1.1)  | PLL Bypass mode, $V_T = 50\%$  | 2800 | 3600 | 4500 | ps    |
| t <sub>PDELAY</sub>  | Propergation delay   | PLL mode, $V_T = 50\%$   | 0    | 90   | 200  | ps    |
| tj <sub>c-c</sub>    | Cycle to cycle jitter <sup>(1,2)</sup>   |  |      | 14   | 50   | ps    |
|                      |  | PCIe Gen 1   | 20   | 22   | 86   | ps    |
|                      |  | PCIe Gen 2 Low Band, 10kHz < f < 1.5MHz  | 0.2  | 0.3  | 3.0  | ps    |
|                      | Integrated phase jitter (RMS) <sup>(1,5,6)</sup>   | PCIe Gen 2 High Band, 1.5MHz < f < Nyquist (50MHz)   | 1.6  | 2.0  | 3.1  | ps    |
| tj <sub>PHASE</sub>  |  | PCIe Gen 3 (PLL BW of 2-4 or 2-5MHz,<br>CDR =10MHz)  | 0.3  | 0.35 | 1.0  | ps    |
|                      |  | PCIe Gen 4 (PLL BW of 2-4 or 2-5MHz,<br>CDR =10MHz)  | 0.2  | 0.3  | 0.5  | ps    |
|                      |  | 125MHz, 1.5MHz to 20MHz, -20dB/decade<br>Rollover < 1.5MHz, -40dB/decade rolloff ><br>10MHz <sup>(9)</sup> |      | 1.9  | 2    | ps    |
|                      |  | PCIe Gen 1   |      | 0.6  | 5    | ps    |
|                      |  | PCIe Gen 2 Low Band, 10kHz < f < 1.5MHz  |      | 0.1  | 0.3  | ps    |
|                      |  | PCIe Gen 2 High Band, 1.5MHz < f < Nyquist (50MHz)   |      | 0.05 | 0.1  | ps    |
| tj <sub>PHASEA</sub> | Additive Integrated phase jitter (RMS) <sup>(1,5,10)</sup>   | PCIe Gen 3 (PLL BW of 2-4 or 2-5MHz,<br>CDR =10MHz)  |      | 0.05 | 0.1  | ps    |
|                      | , see the see that | PCIe Gen 4 (PLL BW of 2-4 or 2-5MHz,<br>CDR =10MHz) (BW_SEL_TRI=M)   |      | 0.03 | 0.05 | ps    |
|                      |  | 125MHz, 1.5MHz to 20MHz, -20dB/decade<br>Rollover < 1.5MHz, -40dB/decade rolloff ><br>10MHz                |      | 0.15 | 0.3  | ps    |
| $t_{DC}$             | Duty Cycle <sup>(1,2)</sup>  | Measured differentially, PLL Mode  | 45   | 50   | 55   | %     |
| $t_{\rm DCD}$        | Duty Cycle Distortion <sup>(1,7)</sup>   | Measured differentially, PLL Bypass Mode at 100MHz   | -1   | 0    | 1    | %     |
| t <sub>STARTUP</sub> | Start up time  |  |      |      | 10   | ms    |





| Symbol            | Parameters    | Condition | Min. | Тур. | Max. | Units |
|-------------------|---------------|-----------|------|------|------|-------|
| t <sub>LOCK</sub> | PLL lock time |           |      |      | 20   | ms    |

### Note:

- 1. Guaranteed by design and characterization, not 100% tested in production
- 2. Measured from differential waveform
- 3. Slew rate is measured through the Vswing voltage range centered around differential 0V, within +/-150mV window
- 4. Slew rate matching is measured using a +/-75mV window centered on differential zero
- 5. See http://www.pcisig.com for complete specs
- 6. Sample size of at least 100k cycles. This can be extrapolated to 108ps pk-pk @ 1M cycles for a BER of  $10^{-12}\,$
- 7. Duty cycle distortion is the difference in duty cycle between the out and input clock when te device is operated in the PLL bypass mode
- $8. \ The \ Min \ and \ Max \ values \ of \ each \ BW \ setting \ track \ each \ other, low \ BW \ max \ will \ never \ occur \ with \ high \ BW \ min$
- 9. Applies to all differential outputs
- 10. For additive jitter RMS value is calculated by the following equation = SQRT [(total jitter) $^{*2}$  (input jitter) $^{*2}$ ]





## **SMBus Serial Data Interface**

The PI6CB18200 is a slave only device that supports block read and block write protocol using a single 7-bit address and read/write bit as shown below.

Read and write block transfers can be stopped after any complete byte transfer.

## **Address Assignment**

| A6 | A5 | A4 | A3 | A2 | A1 | A0 | R/W |
|----|----|----|----|----|----|----|-----|
| 1  | 1  | 0  | 1  | 1  | 0  | 1  | 1/0 |

Note: SMbus address is DA in hex.

### **How to Write**

| 1 bit     | 7 bits | 1 bit | 1 bit | 8 bits                              | 1 bit | 8 bits                 | 1 bit | 8 bits                  | 1 bit | 8 bits                   | 1 bit | 1 bit    |
|-----------|--------|-------|-------|-------------------------------------|-------|------------------------|-------|-------------------------|-------|--------------------------|-------|----------|
| Start bit | Add.   | W(0)  | Ack   | Beginning<br>Byte loca-<br>tion = N | Ack   | Data Byte<br>count = X | Ack   | Beginning Data Byte (N) | Ack   | <br>Data Byte<br>(N+X-1) | Ack   | Stop bit |

### **How to Read**

| 1 bit     | 7 bits  | 1 bit | 1 bit | 8 bits                              | 1 bit | 1 bit               | 7 bits  | 1 bit | 1 bit | 8 bits                 | 1 bit | 8 bits                        | 1 bit |
|-----------|---------|-------|-------|-------------------------------------|-------|---------------------|---------|-------|-------|------------------------|-------|-------------------------------|-------|
| Start bit | Address | W(0)  | Ack   | Beginning<br>Byte loca-<br>tion = N | Ack   | Repeat<br>Start bit | Address | R(1)  | Ack   | Data Byte<br>count = X | Ack   | Beginning<br>Data Byte<br>(N) | Ack   |

| 8 bits    | 1 bit | 1 bit    |
|-----------|-------|----------|
| Data Byte | NAck  | Stop bit |
| (N+X-1)   | INACK | Stop bit |





# Byte 0: Output Enable Register<sup>(1)</sup>

| Bit | Control Function | Description      | Type | Power Up<br>Condition | 0       | 1       |
|-----|------------------|------------------|------|-----------------------|---------|---------|
| 7   | Reserved         |                  |      | 1                     |         |         |
| 6   | Reserved         |                  |      | 1                     |         |         |
| 5   | Q1_OE            | Q1 output enable | RW   | 1                     | Low/Low | Enabled |
| 4   | Reserved         |                  |      | 1                     |         |         |
| 3   | Q0_OE            | Q0 output enable | RW   | 1                     | Low/Low | Enabled |
| 2   | Reserved         |                  |      | 1                     |         |         |
| 1   | Reserved         |                  |      | 1                     |         |         |
| 0   | Reserved         |                  |      | 1                     |         |         |

#### Note:

1. A low on these bits will override the OE# pins and force the differential outputs to Low/Low states

## Byte 1: PLL Operating Mode and Output Amplitude Control Register

| Bit | Control Function | Description                   | Туре              | Power Up<br>Condition | 0                                    | 1                                    |
|-----|------------------|-------------------------------|-------------------|-----------------------|--------------------------------------|--------------------------------------|
| 7   | PLLMODERB1       | PLL Mode Readback Bit1        | R                 | Latch                 | C DI I O                             | : M - d - T-1-1-                     |
| 6   | PLLMODERB0       | PLL Mode Readback Bit0        | R                 | Latch                 | See PLL Operat                       | ing Mode Table                       |
| 5   | PLLMODE_SWCTR    | Enable SW control of PLL Mode | RW                | 0                     | Values in<br>B1[7:6] set PLL<br>Mode | Values in<br>B1[4:3] set PLL<br>Mode |
| 4   | PLLMODE1         | PLL Mode control Bit1         | RW <sup>(1)</sup> | 0                     | See PLL Operat                       | ing Mode Table                       |
| 3   | PLLMODE0         | PLL Mode control Bit0         | RW <sup>(1)</sup> | 0                     | See PLL Operat                       | ing widde rabie                      |
| 2   | Reserved         |                               |                   | 1                     |                                      |                                      |
| 1   | Amplitude1       | Control output amplitudo      | RW                | 1                     | '00' = 0.6V, '01' =                  | = 0.7V, '10' =                       |
| 0   | Amplitude0       | Control output amplitude      | RW                | 0                     | 0.8V, '11' = 0.9V                    |                                      |

### Note:

1. B1[5] must be set to a 1 for these bits to have any effect on the part





# Byte 2: Differential Output Slew Rate Control Register

| Bit | Control Function | Description             | Туре | Power Up<br>Condition | 0            | 1            |
|-----|------------------|-------------------------|------|-----------------------|--------------|--------------|
| 7   | Reserved         |                         |      | 1                     |              |              |
| 6   | Reserved         |                         |      | 1                     |              |              |
| 5   | SLEWRATECTR_Q1   | Control slew rate of Q1 | RW   | 1                     | Slow setting | Fast setting |
| 4   | Reserved         |                         |      | 1                     |              |              |
| 3   | SLEWRATECTR_Q0   | Control slew rate of Q0 | RW   | 1                     | Slow setting | Fast setting |
| 2   | Reserved         |                         |      | 1                     |              |              |
| 1   | Reserved         |                         |      | 1                     |              |              |
| 0   | Reserved         |                         |      | 1                     |              |              |

# **Byte 3: Frequency Select Control Register**

| Bit | Control Function | Description                         | Туре              | Power Up<br>Condition | 0                                 | 1                                |
|-----|------------------|-------------------------------------|-------------------|-----------------------|-----------------------------------|----------------------------------|
| 7   | Reserved         |                                     |                   | 1                     |                                   |                                  |
| 6   | Reserved         |                                     |                   | 1                     |                                   |                                  |
| 5   | FREQ_SEL_EN      | Enable SW selection of frequency    | RW                | 0                     | SW Freq.<br>selection<br>disabled | SW Freq.<br>selection<br>enabled |
| 4   | FSEL1            | Freq. Select Bit 1                  | RW <sup>(1)</sup> | 0                     | Coo Engavon av                    | Calaat Tabla                     |
| 3   | FSEL0            | Freq. Select Bit 0                  | RW <sup>(1)</sup> | 0                     | See Frequency                     | select Table                     |
| 2   | Reserved         |                                     |                   | 1                     |                                   |                                  |
| 1   | Reserved         |                                     |                   | 1                     |                                   |                                  |
| 0   | SLEWRATESEL FB   | Adjust Slew Rate of Feedback signal | RW                | 1                     | 2.0V/ns                           | 3.0V/ns                          |

### Note:

## **Byte 4: Reserved**

| Bit | <b>Control Function</b> | Description | Type | Power Up<br>Condition | 0 | 1 |
|-----|-------------------------|-------------|------|-----------------------|---|---|
| 7:0 | Reserved                |             |      | 1                     |   |   |

<sup>1.</sup> B1[5] must be set to a 1 for these bits to have any effect on the part





# Byte 5: Revision and Vendor ID Register

| Bit | Control Function | Description | Туре | Power Up<br>Condition | 0 1           |  |
|-----|------------------|-------------|------|-----------------------|---------------|--|
| 7   | RID3             |             | R    | 0                     |               |  |
| 6   | RID2             | Revision ID | R    | 0                     | rev = 0000    |  |
| 5   | RID1             |             | R    | 0                     |               |  |
| 4   | RID0             |             | R    | 0                     |               |  |
| 3   | PVID3            | Vendor ID   | R    | 0                     |               |  |
| 2   | PVID2            |             | R    | 0                     | D: 1 0011     |  |
| 1   | PVID1            |             | R    | 1                     | Diodes = 0011 |  |
| 0   | PVID0            |             | R    | 1                     |               |  |

# **Byte 6: Device Type/Device ID Register**

| Bit | <b>Control Function</b> | Description | Туре | Power Up<br>Condition | 0                          | 1     |
|-----|-------------------------|-------------|------|-----------------------|----------------------------|-------|
| 7   | DTYPE1                  |             | R    | 0                     | '00' = CG, '01' =          | ZDB,  |
| 6   | DTYPE0                  | Device type | R    | 1                     | '10' = Reserve, '11' = ZDB |       |
| 5   | DID5                    |             | R    | 0                     |                            |       |
| 4   | DID4                    |             | R    | 0                     | 000010 binary 02Hov        |       |
| 3   | DID3                    | Device ID   | R    | 0                     |                            | 02Uov |
| 2   | DID2                    | Device ID   | R    | 0                     | - 000010 binary, 02Hex     |       |
| 1   | DID1                    |             | R    | 1                     |                            |       |
| 0   | DID0                    |             | R    | 0                     |                            |       |

# **Byte 7: Byte Count Register**

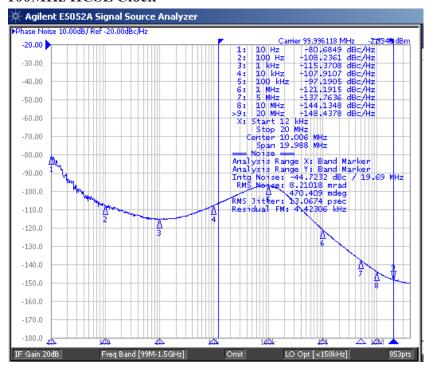
| Bit | Control Function | Description            | Туре | Power Up<br>Condition | 0                                | 1               |
|-----|------------------|------------------------|------|-----------------------|----------------------------------|-----------------|
| 7   | Reserved         |                        |      | 0                     |                                  |                 |
| 6   | Reserved         |                        |      | 0                     |                                  |                 |
| 5   | Reserved         |                        |      | 0                     |                                  |                 |
| 4   | BC4              |                        | RW   | 0                     |                                  |                 |
| 3   | BC3              |                        | RW   | 1                     | Writing to this                  | register will   |
| 2   | BC2              | Byte count programming | RW   | 0                     | configure how                    | many bytes will |
| 1   | BC1              |                        | RW   | 0                     | be read back, default is 8 bytes |                 |
| 0   | BC0              |                        | RW   | 0                     |                                  |                 |





## **Plots**

### 100MHz HCSL Clock



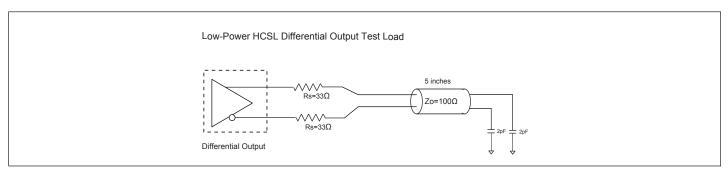


Figure 1. Low Power HCSL Test Circuit

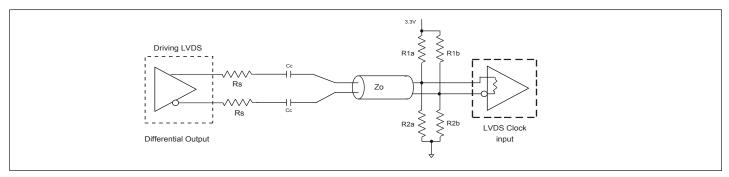


Figure 2. Differential Output Driving LVDS





# **Alternate Differential Output Terminations**

| Component                         | Receiver with termination | Receiver without termination | Unit |  |
|-----------------------------------|---------------------------|------------------------------|------|--|
| R <sub>1a</sub> , R <sub>1b</sub> | 10,000                    | 140                          | Ω    |  |
| $R_{2a}, R_{2b}$                  | 5,600                     | 75                           | Ω    |  |
| C <sub>C</sub>                    | 0.1                       | 0.1                          | μF   |  |
| $V_{CM}$                          | 1.2                       | 1.2                          | V    |  |

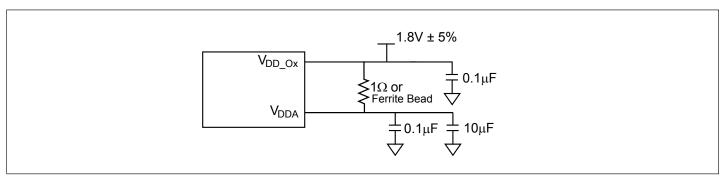


Figure 3. Power Supply Filter

# **Part Marking**

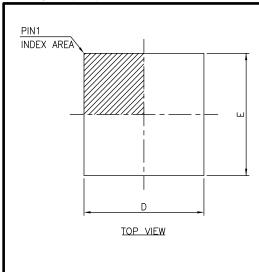




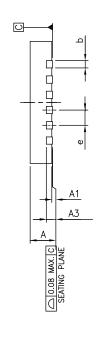


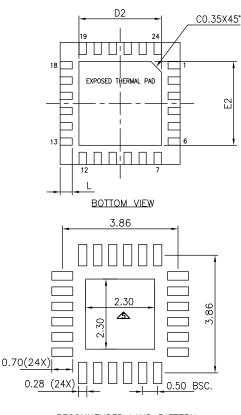
# **Packaging Mechanical**

## 24-TQFN (ZD)



| SYMBOLS | MIN. | NOM.      | MAX. |  |  |
|---------|------|-----------|------|--|--|
| Α       | 0.80 | 0.85      | 0.90 |  |  |
| A1      | 0.00 | 0.02      | 0.05 |  |  |
| A3      | 0.   | 0.20 REF. |      |  |  |
| b       | 0.18 | 0.25      | 0.30 |  |  |
| D       | 3.90 | 4.00      | 4.10 |  |  |
| E       | 3.90 | 4.00      | 4.10 |  |  |
| е       | 0    | .50 BS    | SC   |  |  |
| D2      | 2.15 | _         | 2.75 |  |  |
| E2      | 2.15 | _         | 2.75 |  |  |
| L       | 0.35 | 0.40      | 0.45 |  |  |





RECOMMENDED LAND PATTERN

### NOTE :

- 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
- 2. COPLANARITY APPLIES TO THE EXPOSED THERMAL PAD AS WELL AS THE TERMINALS.
- 3. REFER JEDEC MO-220
- 4. RECOMMENDED LAND PATTERN IS FOR REFERENCE ONLY.
- 5. THERMAL PAD SOLDERING AREA
- 6. MAJOR EDAP D2XE2=2.25X2.25

DESCRIPTION: 24-Contact, Very Thin Quad Flat No-Lead (TQFN)

PACKAGE CODE: ZD (ZD24)

DOCUMENT CONTROL #: PD-2100

REVISION: C

17-0533

### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

# **Ordering Information**

| Ordering Code Package Code |    | Package Description                            | Pin 1 Location   |  |
|----------------------------|----|--|------------------|--|
| PI6CB18200ZDIEX            | ZD | 24-Contact, Very Thin Quad Flat No-Lead (TQFN) | Top Right Corner |  |
| PI6CB18200ZDIEX-13R        | ZD | 24-Contact, Very Thin Quad Flat No-Lead (TQFN) | Top Left Corner  |  |

### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. I = Industrial
- 5. E = Pb-free and Green
- 6. X suffix = Tape/Reel
- 7. For packaging detail, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf





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